Product data sheet

1. General description

Triple high-voltage switching diodes, encapsulated in a SOT457 (SC-74/TSOP6) small Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

High switching speed: t_{rr} ≤ 50 ns

Low capacitance: C_d ≤ 5 pF

Reverse voltage: V_R ≤ 200 V

AEC-Q101 qualified

Repetitive peak reverse voltage: V_{RRM} ≤ 250 V
 Repetitive peak forward current: I_{FRM} ≤ 1 A

Small SMD plastic package

3. Applications

- High-voltage switching in surface-mounted circuits
- Automotive
- Communication

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
I _F	forward current	pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$	[1]	-	-	200	mA
V _R	reverse voltage			-	-	200	V
Per diode							
I _R	reverse current	$V_R = 200 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed};$ $t_p \le 300 \mu\text{s}; \delta \le 0.02$		-	25	100	nA
t _{rr}	reverse recovery time	I_F = 30 mA; I_R = 30 mA; $I_{R(meas)}$ = 3 mA; I_{L} = 100 Ω ; I_{L} = 25 °C		-	16	50	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





High-voltage switching diodes

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	<u> </u>	6 5 4
2	K2	cathode (diode 2)		
3	K3	cathode (diode 3)		
4	A3	anode (diode 3)	TSOP6 (SOT457)	
5	A2	anode (diode 2)		006aab241
6	A1	anode (diode 1)		000aab241

6. Ordering information

Table 3. Ordering information

Type number	Package	ige				
	Name	Description	Version			
BAS21VD	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

7. Marking

Table 4. Marking codes

Type number	Marking code
BAS21VD	B5

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode	Per diode					
V_{RRM}	repetitive peak reverse voltage			-	250	V
V_R	reverse voltage			-	200	V
I _F	forward current	pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$	[1]	-	200	mA
I _{FRM}	repetitive peak forward current	t _p ≤ 1 ms; δ ≤ 25 %		-	1	Α
I _{FSM}	non-repetitive peak forward	t_p = 10 μ s; $T_{j(init)}$ = 25 °C; square wave		-	16	Α
	current	t_p = 100 μ s; $T_{j(init)}$ = 25 °C; square wave		-	8	Α
		t_p = 10 ms; $T_{j(init)}$ = 25 °C; square wave		-	2	Α

BAS21VD

High-voltage switching diodes

Symbol	Parameter	Conditions			Min	Max	Unit
Per device; one diode loaded							
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C		[1]	-	250	mW
			1	[2]	-	295	mW
T _{stg}	storage temperature				-65	150	°C
Tj	junction temperature				-	150	°C
T _{amb}	ambient temperature				-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device; on	Per device; one diode loaded						
fro	thermal resistance	in free air	[1]	-	-	500	K/W
	from junction to ambient		[2]	-	-	425	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[3]	-	-	140	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode			,			
V _F	forward voltage	I _F = 100 mA; T _{amb} = 25 °C	-	-	1	V
		I _F = 200 mA; T _{amb} = 25 °C	-	-	1.25	V
I _R	reverse current	V_R = 200 V; pulsed; $t_p \le 300 \text{ μs}$; $\delta \le 0.02$; T_{amb} = 25 °C	-	25	100	nA
		V _R = 200 V; T _j = 150 °C	-	-	100	μA
C _d	diode capacitance	f = 1 MHz; V _R = 0 V; T _{amb} = 25 °C	-	0.6	5	pF
t _{rr}	reverse recovery time	I_F = 30 mA; I_R = 30 mA; T_{amb} = 25 °C; R_L = 100 Ω ; $I_{R(meas)}$ = 3 mA	-	16	50	ns

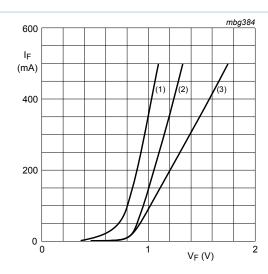
BAS21VD

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[3] Soldering point of cathode tab.

High-voltage switching diodes

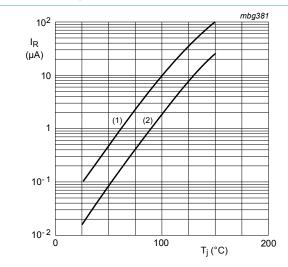


(1) T_j = 150 °C; typical values

(2) T_i = 25 °C; typical values

(3) T_i = 25 °C; maximum values

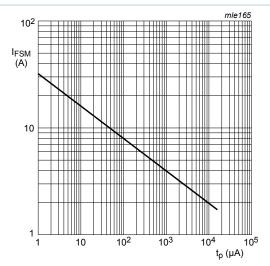
Fig. 1. Forward current as a function of forward voltage



(1) $V_R = V_{Rmax}$; maximum values

(2) $V_R = V_{Rmax}$; typical values

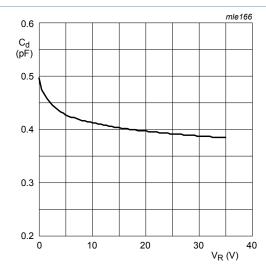
Fig. 3. Reverse current as a function of junction temperature



Based on square wave currents.

T_{i(init)} = 25 °C

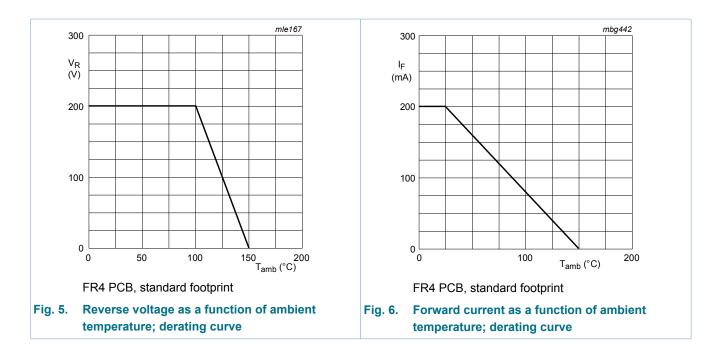
Fig. 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



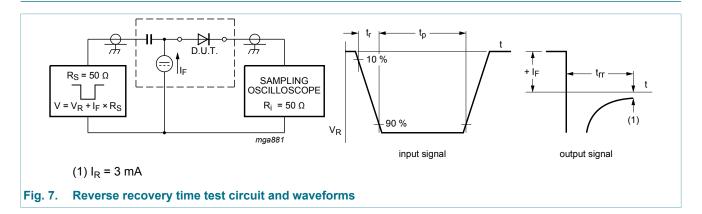
 $f = 1 MHz; T_i = 25 °C$

Fig. 4. Diode capacitance as a function of reverse voltage; typical values

High-voltage switching diodes



11. Test information

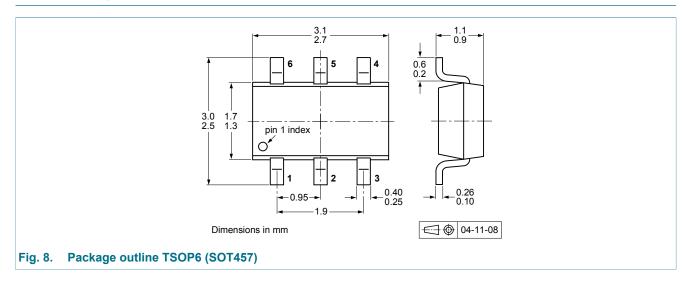


11.1 Quality information

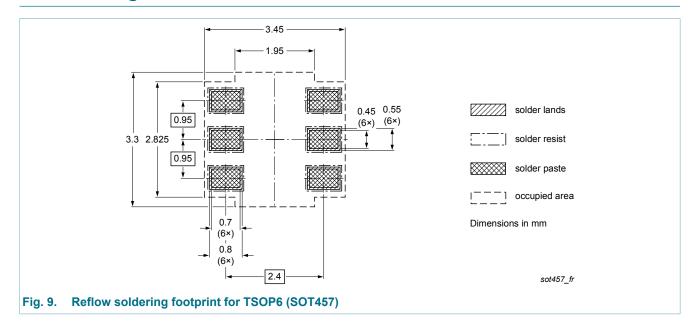
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

High-voltage switching diodes

12. Package outline

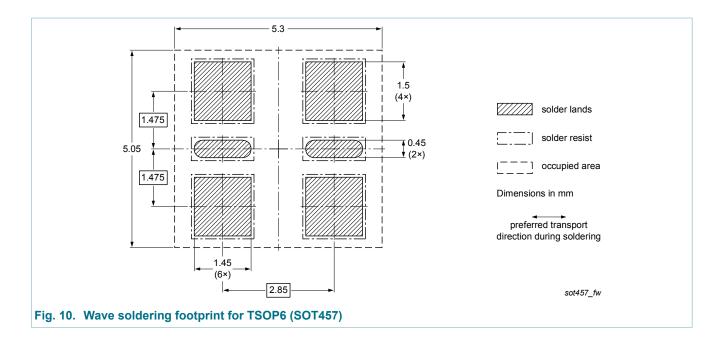


13. Soldering



6/11

High-voltage switching diodes



High-voltage switching diodes

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BAS21VD v.3	20130801	Product data sheet	-	BAS21VD v.2
Modifications:	Table 7. CharactPacking informationLegal information		/ _F corrected	
BAS21VD v.2	20110629	Product data sheet	-	BAS21VD v.1
BAS21VD v.1	20030703	Product data sheet	-	-

High-voltage switching diodes

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BAS21VD

High-voltage switching diodes

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High-voltage switching diodes

16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	2
9	Thermal characteristics	3
10	Characteristics	3
11	Test information	5
11.1	Quality information	5
12	Package outline	6
13	Soldering	6
14	Revision history	8
15	Legal information	9
15.1	Data sheet status	9
15.2	Definitions	9
15.3	Disclaimers	9
15.4	Trademarks	10

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